

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

LV8012T — Forward/Reverse Motor Driver

Overview

LV8012T is a 2ch forward/reverse motor driver IC using D-MOS FET for output stage. As MOS circuit is used, it supports the PWM input. Its features are that the on resistance $(0.75\Omega \text{ typ})$ and current dissipation are low.

It also provides protection functions such as heat protection circuit and reduced voltage detection and is optimal for the motors that need high-current.

Functions

- 2ch forward/reverse motor driver
- Low power consumption
- Built-in charge pump circuit
- Compact TSSOP-24 package
- Possible to respond to 3V control voltage and 6V motor voltage device
- \bullet Low ON resistance 1.2Ω
- Built-in low voltage reset and thermal shutdown circuit
- Four mode function forward/reverse, brake, stop.

Specifications

Absolute Maximum Ratings at Ta = 25°C, SGND = PGND = 0V

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage (For load)	VM max		-0.5 to 7.5	V
Supply voltage (For control)	V _{CC} max		-0.5 to 6.0	V
Output current	I _O max	t ≤ 100ms	1.4	Α
Input voltage	V _{IN} max		-0.5 to V _{CC} +0.5	V
Allowable power dissipation	Pd	* Mounted on a substrate	800	mW
Operating temperature	Topr		-20 to +75	°C
Storage temperature	Tstg		-55 to +150	°C

 $^{^{\}star}$: Mounted on a substrate : 30×50×1.6mm $^{\!3}\!$, glass epoxy board

Caution 1) Absolute maximum ratings represent the value which cannot be exceeded for any length of time.

Caution 2) Even when the device is used within the range of absolute maximum ratings, as a result of continuous usage under high temperature, high current, high voltage, or drastic temperature change, the reliability of the IC may be degraded. Please contact us for the further details.

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LV8012T

Allowable Operating Ratings at Ta = 25°C, SGND = PGND = 0V

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage (VM Pin)	VM		2.0 to 7.0	V
Supply voltage (V _{CC} Pin)	Vcc		2.7 to 5.5	
Input signal voltage	V _{IN}		0 to V _{CC}	V
Input signal frequenc	f max		100	kHz
Capacitor for charge pump	C1, C2, C3		0.001 to 0.1	μF

Electrical Characteristics at Ta = 25°C, $V_{CC} = VM = 5.0V$, SGND = PGND = 0V, unless especially specified.

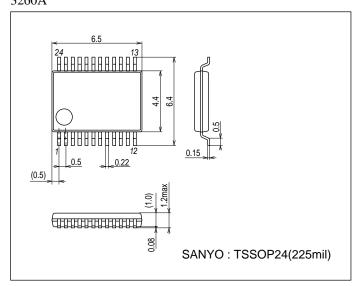
Parameter		0	O III		Ratings			
		Symbol	Conditions	Remarks	min	typ	max	Unit
Supply current for load at standby		IMO	EN = 0V	1			1.0	μΑ
Supply current standby	for control at	ICO	EN = 0V, IN1 = IN2 = IN3 = IN4 = 0V	2			1.0	μΑ
Current drain o	during operation	IC1	EN = 5V, VG at no load	3		0.7	1.2	mA
H-level input vo	oltage	v_{IH}	$2.7V \le V_{CC} \le 5.5V$		0.6×V _{CC}		Vcc	V
L-level input vo	oltage	V_{IL}	$2.7V \le V_{CC} \le 5.5V$		0		0.2×V _{CC}	V
H-level input co (IN1, IN2, IN3,		lН		4			1.0	μΑ
L-level input current (IN1, IN2, IN3, IN4)		Ŀ		4	-1.0			μΑ
Pull-down resistance (EN1, 2)		RUP			100	200	400	kΩ
Output ON resistance		RON	Sum of ON resistances at top and bottom	5		0.75	1.2	Ω
Charge pump voltage		VG		6	8.5		10.5	V
Low-voltage detection operation voltage		VCS		7	2.15	2.30	2.45	V
Thermal shutdown operation temperature		T _{TSD}		8		180		°C
Charge pump capacity (IG = 500μA)		VGLOAD		9	8	9		V
IG current dissipation (Fin = 20kHz)		IG		10			350	μΑ
Charge pump start time		TVG	CVG = 0.1μF	11			1.0	ms
Output block	Turn on time	TPLH		12		0.2	0.4	μS
	Turn off time	TPHL		12		0.2	0.4	μS

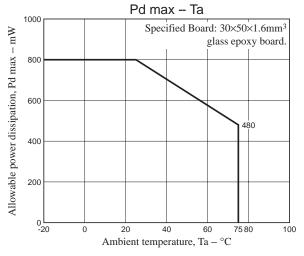
Remarks

- 1. It shows current dissipation of VM pin in output OFF state.
- 2. It shows current dissipation of V_{CC} pin in stand-by state. (The standard current depends on EN pin pull-down resistance.)
- 3. It shows current dissipation of V_{CC} pin in state of EN = 5V (stand-by), including current dissipation of VG pin.
- 4. For IN1, IN2, IN3 and IN4 pins, no pull-down and pull-up resistance is needed. (High impedance pin)
- 5. It shows sum of upper and lower saturation voltages of OUT pin.
- 6. It controls charge-pump oscillation and makes specified voltage.
- 7. When low voltage is detected, the lower output is turned OFF.
- 8. When thermal protection circuit is activated, the lower output is turned OFF. When the heat temperature is fallen, it is turned ON again.
- 9. IG (VG pin load current) = 500μ A
- 10. It shows VG pin current dissipation in state of PWM input for IN pin.
- 11. It specifies start-up time from 10% to 90% when VG is in non-load state (when setting the capacitor between VG and GND to $0.1\mu F$ and V_{CC} is 5V).
- 12. It specifies 10% to 90% for start-up and 90% to 10% for shut-down.

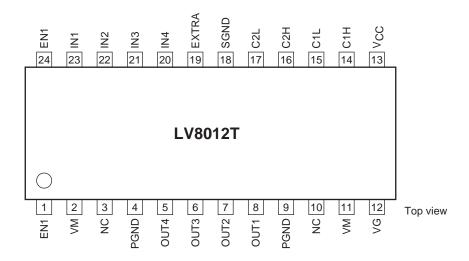
Package Dimensions

unit : mm (typ) 3260A

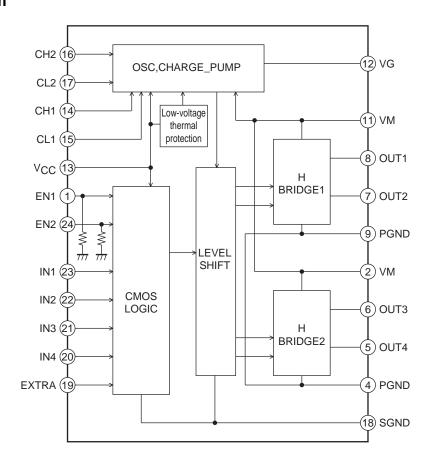




Pin Assignment



Block Diagram



Truth table

	EN1	IN1	IN2	OUT1	OUT2	Circuit of	
EXTRA		IIN 1	INZ	0011	0012		Mode
	(EN2)	(IN3)	(IN4)	(OUT3)	(OUT4)	Charge Pump	540
L	Н	Н	Н	Z	Z	ON	Standby
		Н	L	L	Н		Reverse
		L	Н	Н	L		Forward
		L	L	L	L		Brake
	L	-	-	L	L	OFF	Standby
Н	Н	Н	-	L	Н	ON	Reverse
		L	-	Н	L		Forward
	L	-	-	L	L		Brake

-: Don't care Z: High-Impedance

^{*} Current drain becomes zero in the standby mode.

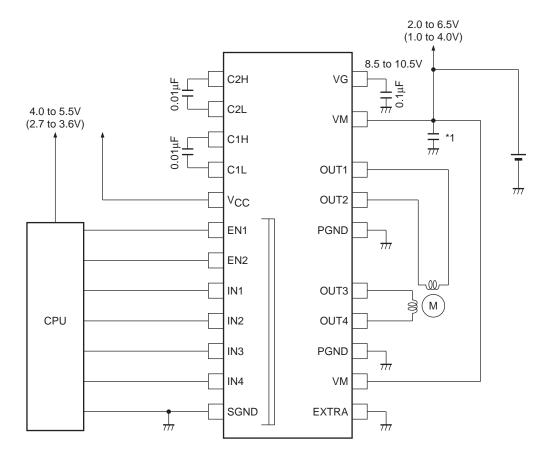
^{*} The output side becomes OFF, with motor drive stopped, during voltage reduction and thermal protection.

LV8012T

Pin Functions

Pin Fun Pin No.	Pin name	Function	Equivalent Circuit
15	C1L	Voltage raising capacitor connection pin	
17	C2L	. Stage talesting supulsion confliction pin	V _C C
			
14	C1H	Voltage raising capacitor connection pin	->-\\(\frac{1}{2} \) \(\frac{1}{2} \) \(
16	C2H		
			C1H () \$
			C1H
			C2H O
23	IN1	Driver output changeover	Vcc
22 21	IN2 IN3		+
20	IN4		† .
19	EXTRA		__
			*
	EN14	Lasis arabia sia	777
1 24	EN1 EN2	Logic enable pin TOUT output control pin	Vcc
	<u>-</u>	(Pull-down resistor incorporated)	
			W = 20010
			₹ 200kΩ π π
8	OUT1	Driver output pin	VM
7	OUT2		\bigcirc
6 5	OUT3 OUT4		
	PGND		, <u>,</u> ,,
			оит
			PGND
2	VM	Motor power supply	
11 13	VM VCC	(both terminals to be connected) Logic power supply	
12	VG	Driver drive circuit power supply	
	-		VG
			-0.1μF
			C2H
			0.01µF
			C2L O
18	SGND	Logic GND	
9	PGND PGND	Driver GND (both terminals to be connected)	
4	FUND	(Dour terrillials to be conflected)	

Sample Application Circuit



- *1 : Connect a kickback absorption capacitor directly near IC. Coil kickback may cause rise of the voltage of VM line, and the voltage exceeding the maximum rating may be applied momentarily, resulting in deterioration or damage of IC.
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